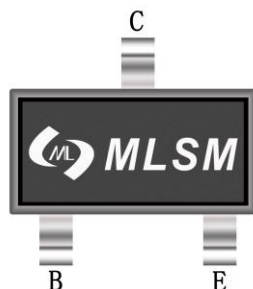
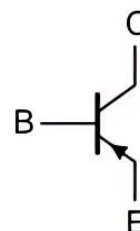


Features

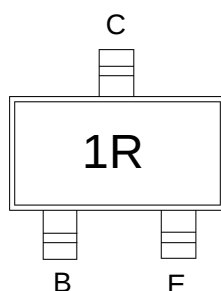
- Small Package Low $V_{CE(sat)}$
- High collector current capability I_C and I_{CM}
- High collector current gain (h_{FE}) at high I_C
- High efficiency due to less heat generation
- Required Small Printed-Circuit Board (PCB) area
- Complementary to MLS2515



SOT-523 top view



Schematic diagram



Marking and pin assignment



Halogen-Free

Maximum Ratings (Ta=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	-15	V
V_{CEO}	Collector-Emitter Voltage	-15	V
V_{EBO}	Emitter-Base Voltage	-6	V
I_C	Collector Current	-0.5	A
I_{CM}	Collector Current-Peak	-1	A
P_C	Collector Power Dissipation	150	mW
$R_{\theta JA}$	Thermal Resistance From Junction To Ambient	833	°C/W
T_J, T_{stg}	Operation Junction and Storage Temperature Range	-55~+150	°C

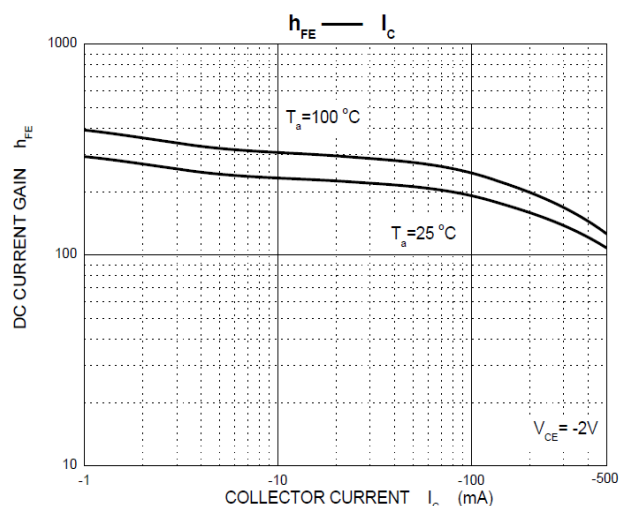
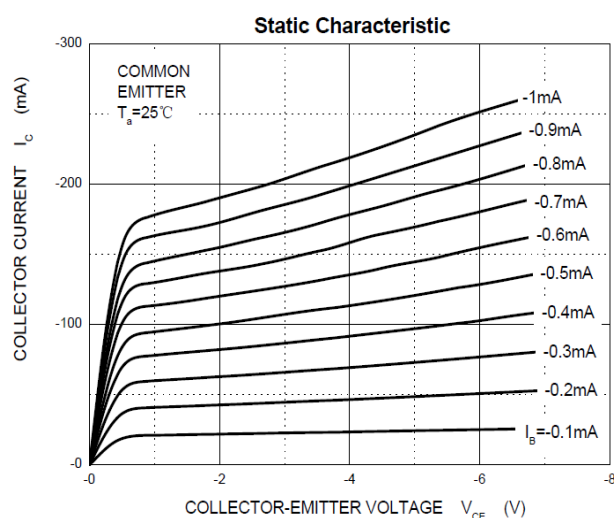
Ordering Information (Example)

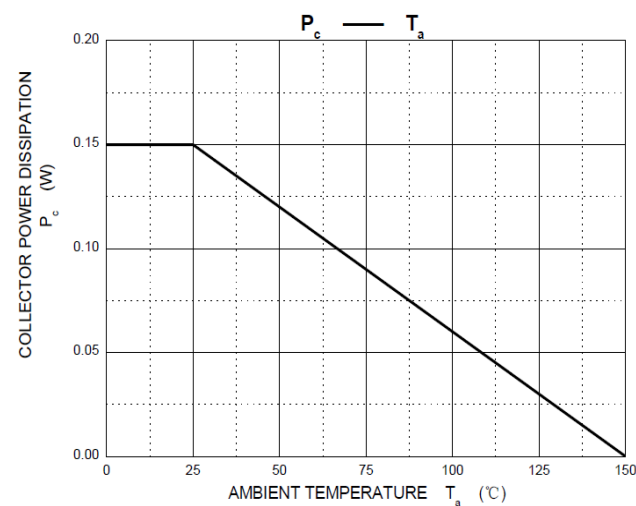
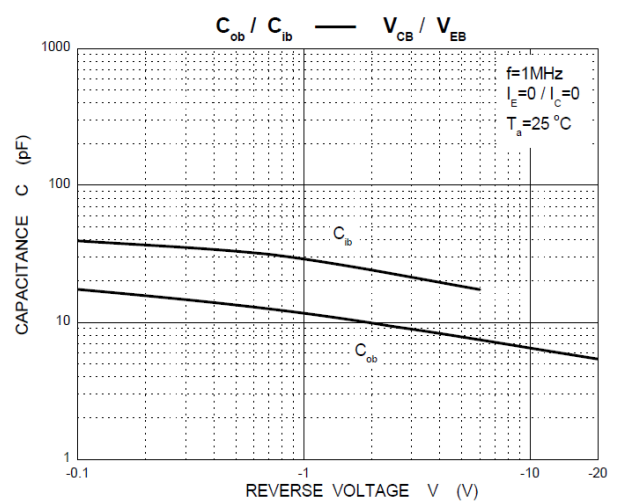
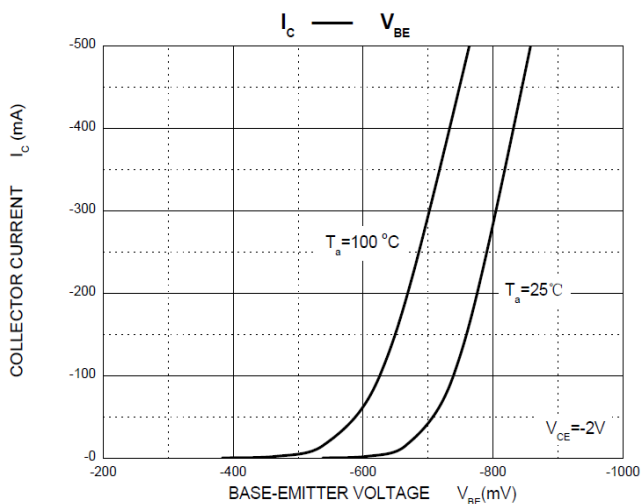
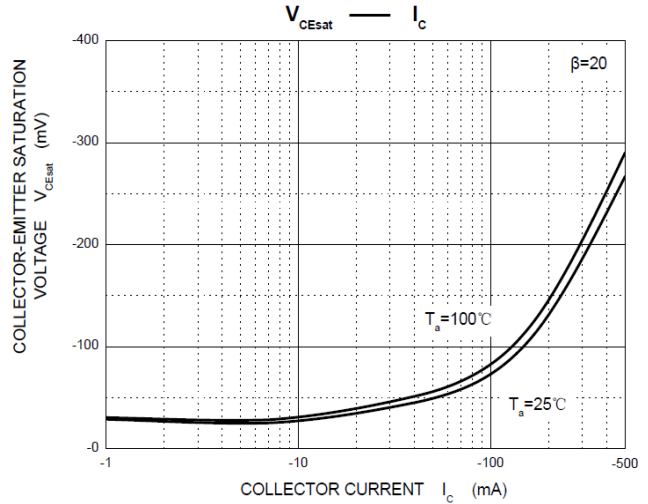
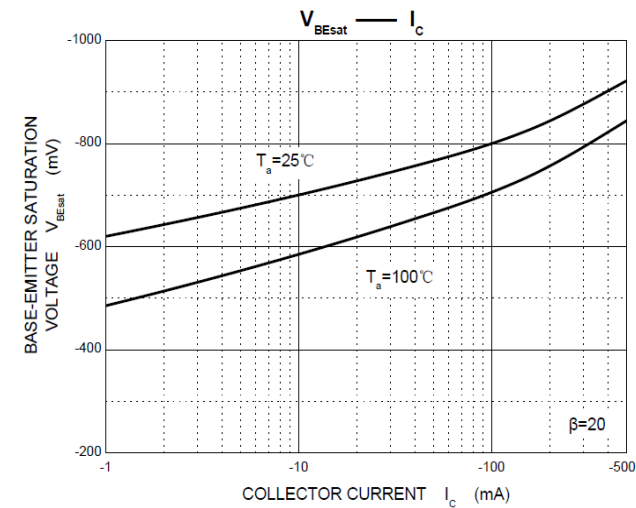
Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MLS3515	SOT-523	1R	3,000	45,000	180,000	7" reel

Electrical Characteristics (Ta=25°C unless otherwise specified)

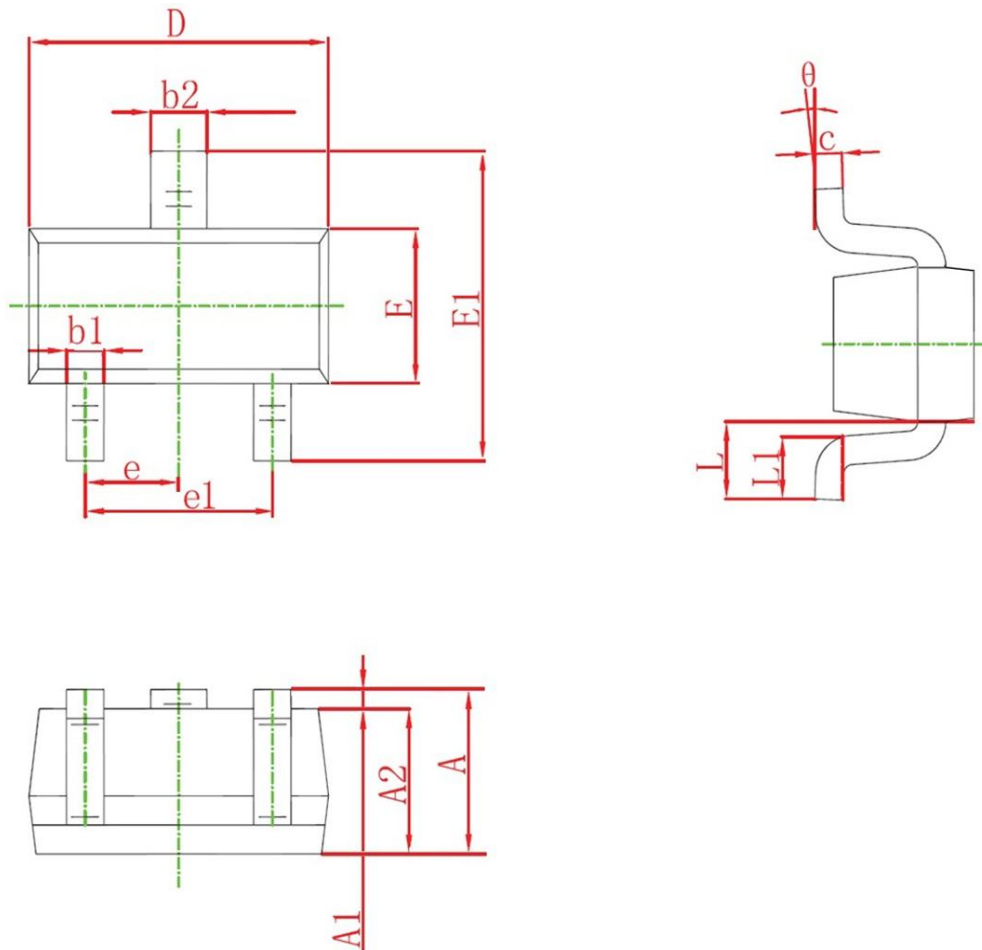
Symbol	Parameter	Condition	Min	Typ	Max	Unit
$V_{(BR)CBO}$	Collector-base breakdown voltage	$I_C = -0.1mA, I_E = 0$	-15	--	--	V
$V_{(BR)CEO}$	Collector-emitter breakdown voltage	$I_C = -10mA, I_B = 0$	-15	--	--	V
$V_{(BR)EBO}$	Emitter-base breakdown voltage	$I_E = -0.1mA, I_C = 0$	-6	--	--	V
I_{EBO}	Emitter cut-off current	$V_{EB} = -5V, I_C = 0$	--	--	-100	nA
I_{CEO}	Collector cut-off current	$V_{CE} = -15V, I_B = 0$	--	--	-100	nA
$H_{FE(1)}^*$	DC current gain	$V_{CE} = -2V, I_C = -10mA$	200	--	500	
$H_{FE(2)}^*$		$V_{CE} = -2V, I_C = -100mA$	150	--	500	
$H_{FE(3)}^*$		$V_{CE} = -2V, I_C = -500mA$	90	--	--	
$V_{CE(sat)1}^*$	Collector-emitter saturation voltage	$I_C = -10mA, I_B = -0.5mA$	--	--	0	mV
$V_{CE(sat)2}^*$		$I_C = -200mA, I_B = -10mA$	--	--	-150	mV
$V_{CE(sat)3}^*$		$I_C = -500mA, I_B = -50mA$	--	--	-250	mV
$V_{BE(sat)}^*$	Base-emitter saturation voltage	$I_C = -500mA, I_B = -50mA$	--	--	-1.1	V
$V_{BE(on)}^*$	Base-emitter voltage	$V_{CE} = -2V, I_C = -100mA$	--	--	-0.9	V
f_T	Transition frequency	$V_{CE} = -5V, I_C = -100mA, f = 100MHz$	100	--	--	MHz

*Pulsetest: pulsewidth $\leq 300\mu s$, duty cycle $\leq 2.0\%$.

Typical Characteristics




SOT-523 Package information



Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	0.700	0.900	0.028	0.035
A1	0.000	0.100	0.000	0.004
A2	0.700	0.800	0.028	0.031
b1	0.150	0.250	0.006	0.010
b2	0.250	0.350	0.010	0.014
c	0.100	0.200	0.004	0.008
D	1.500	1.700	0.059	0.067
E	0.700	0.900	0.028	0.035
E1	1.450	1.750	0.057	0.069
e	0.500TYP		0.020TYP	
e1	0.900	1.100	0.035	0.043
L	0.400REF		0.016REF	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°